

# RV1S2285A

R08DS0186EJ0100

OPERATING AMBIENT TEMPERATURE 115°C, AC INPUT RESPONSE  
4-PIN SSOP WITH 8.2mm CREEPAGE DISTANCE (LSSOP) PHOTOCOUPLER

Rev.1.00

Nov 11, 2019

## DESCRIPTION

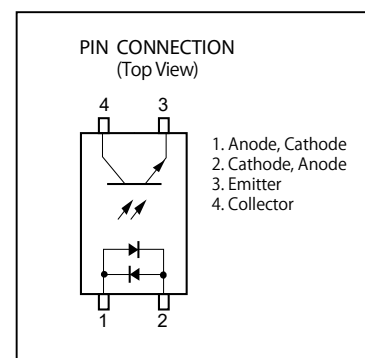
The RV1S2285A is an optically coupled isolator containing GaAs light emitting diodes and an NPN silicon phototransistor.

This package is very small and thin with long creepage distance(8.2mm).

This small product is suitable for various interface circuits which require surface mounting and high-density mounting.

## FEATURES

- Small and long creepage (8.2 mm, LSSOP)
- AC input response
- Operating ambient temperature: 115°C
- High isolation voltage (BV = 5000 Vr.m.s.)
- Embossed tape product : RV1S2285ACCSP-10Yx#KC0 : 3500 pcs/reel
- Pb-Free product
- Safety standard
  - UL : UL1577, Double protection
  - CSA : CAN/CSA-C22.2 No.62368-1, Reinforced insulation
  - VDE : DIN EN 60747-5-5 (Option)

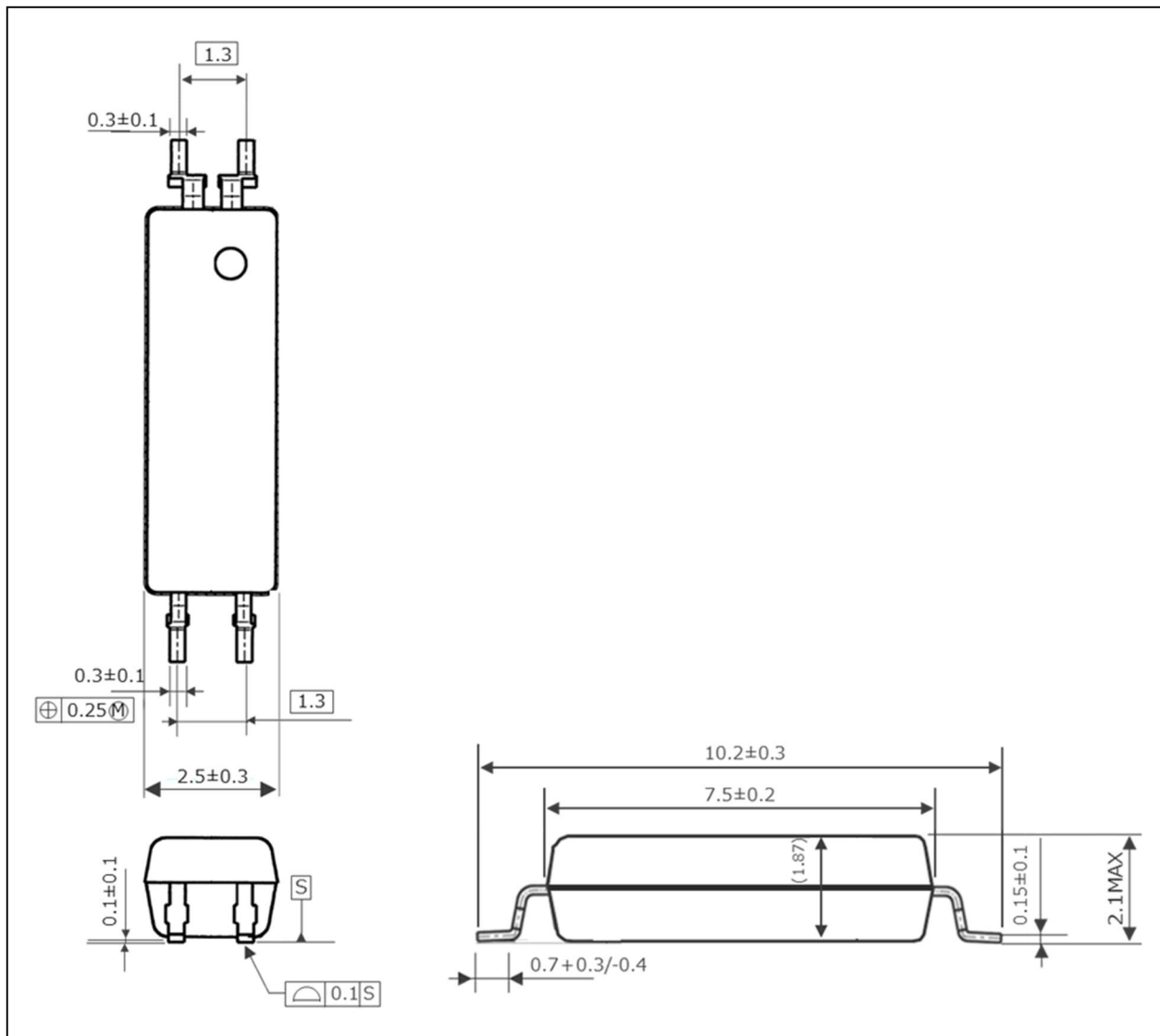


## APPLICATIONS

- Robot controller
- Industrial inverter
- AC Servo
- Programmable logic controller
- Measurement equipment
- Power supply

Start of mass production  
Nov.2019

## PACKAGE DIMENSIONS (UNIT : mm)

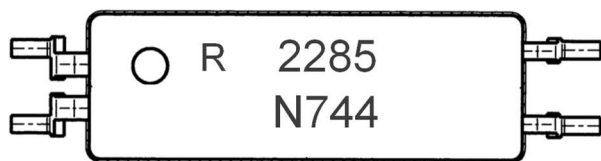


Weight : 0.075g (Typ.)

## PHOTOCOUPLER CONSTRUCTIONS

| Parameter          | UNIT (MIN.) |
|--------------------|-------------|
| Air Distance       | 8.2 mm      |
| Creepage Distance  | 8.2 mm      |
| Isolation Distance | 0.15 mm     |

## MARKING EXAMPLE



|      |     |                         |                                 |
|------|-----|-------------------------|---------------------------------|
| R    |     | An initial of "Renesas" |                                 |
| 2285 |     | Product Part Number *   |                                 |
| O    |     | No.1 pin Mark           |                                 |
| N744 | N   | Rank Code               |                                 |
|      | 744 | Assembly Lot            |                                 |
|      |     | 7                       | Last one-digit of Assembly Year |
|      |     | 44                      | Weekly Serial Code              |

\* ) Applicable type numbers listed below

RV1S 2285 ACCSP-10Yx

Marking type number. " RV1S" and "ACCSP-10Yx" " are omitted from original type number

## ORDERING INFORMATION

| Part Number        | Order Number           | Solder Plating Specification <sup>*1</sup> | Packing Style               | Safety Standard Approval             | Application Part Number <sup>*2</sup> |  |
|--------------------|------------------------|--------------------------------------------|-----------------------------|--------------------------------------|---------------------------------------|--|
| RV1S2285ACCSP-10YC | RV1S2285ACCSP-10YC#SC0 | Pb-Free and Halogen Free (Ni/Pd/Au)        | 20 pcs(Tape 20 pcs cut)     | Standard products (UL, CSA approved) | RV1S2285A                             |  |
|                    | RV1S2285ACCSP-10YC#KC0 |                                            | Embossed Tape 3500 pcs/reel |                                      |                                       |  |
| RV1S2285ACCSP-10YV | RV1S2285ACCSP-10YV#SC0 |                                            | 20 pcs(Tape 20 pcs cut)     | UL, CSA, DIN EN 60747-5-5 approved   |                                       |  |
|                    | RV1S2285ACCSP-10YV#KC0 |                                            | Embossed Tape 3500 pcs/reel |                                      |                                       |  |

Notes:\*1. When specifying CTR rank, please add "/CTR rank" after Order Number.

ex. L rank : RV1S2285ACCSP-10YC#SC0/L

Notes:\*2. For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub>=25°C, unless otherwise specified)

| Parameter                     |                              | Symbol              | Ratings    | Unit    |
|-------------------------------|------------------------------|---------------------|------------|---------|
| Diode                         | Forward Current (DC)         | I <sub>F</sub>      | ±30        | mA      |
|                               | Power Dissipation Derating*1 | ΔP <sub>D</sub> /°C | 0.6        | mW/°C   |
|                               | Power Dissipation            | P <sub>D</sub>      | 60         | mW      |
|                               | Peak Forward Current*2       | I <sub>FP</sub>     | ±0.5       | A       |
| Transistor                    | Collector to Emitter Voltage | V <sub>CEO</sub>    | 80         | V       |
|                               | Emitter to Collector Voltage | V <sub>ECO</sub>    | 5          | V       |
|                               | Collector Current            | I <sub>C</sub>      | 30         | mA      |
|                               | Power Dissipation Derating*1 | ΔP <sub>C</sub> /°C | 1.2        | mW/°C   |
|                               | Power Dissipation            | P <sub>C</sub>      | 120        | mW      |
| Isolation Voltage*3           |                              | BV                  | 5000       | Vr.m.s. |
| Operating Ambient Temperature |                              | T <sub>A</sub>      | -40 ~ +115 | °C      |
| Storage Temperature           |                              | T <sub>stg</sub>    | -40 ~ +125 | °C      |

\*1 Derating from T<sub>A</sub> = 25°C

\*2 PW = 100 μs, Duty Cycle = 1%

\*3 AC voltage for 1 minute at T<sub>A</sub> = 25°C, RH = 60% between input and output.

Pins 1-2 shorted together, 3-4 shorted together.

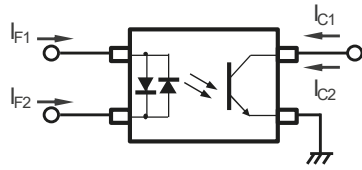
ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C )

| Parameter  |                                                             | Symbol                | Conditions                                                              | MIN.             | TYP. | MAX. | Unit |
|------------|-------------------------------------------------------------|-----------------------|-------------------------------------------------------------------------|------------------|------|------|------|
| Diode      | Forward Voltage                                             | V <sub>F</sub>        | I <sub>F</sub> = ±5 mA                                                  |                  | 1.15 | 1.4  | V    |
|            | Terminal Capacitance                                        | C <sub>t</sub>        | V = 0 V, f = 1 MHz                                                      |                  | 20   |      | pF   |
| Transistor | Collector to Emitter Dark Current                           | I <sub>CEO</sub>      | I <sub>F</sub> =0mA, V <sub>CE</sub> =80V                               |                  |      | 100  | nA   |
| Coupled    | Current Transfer Ratio (I <sub>C</sub> /I <sub>F</sub> ) *1 | CTR                   | I <sub>F</sub> = ±5 mA, V <sub>CE</sub> = 5 V                           | 50               | 200  | 400  | %    |
|            | CTR1/CTR2 注2                                                | CTR1/CTR2             | I <sub>F</sub> = ±5 mA, V <sub>CE</sub> = 5 V                           | 0.3              | 1.0  | 3.0  |      |
|            | Collector Saturation Voltage                                | V <sub>CE (sat)</sub> | I <sub>F</sub> = ±10 mA, I <sub>C</sub> = 2 mA                          |                  |      | 0.3  | V    |
|            | Isolation Resistance                                        | R <sub>I-O</sub>      | V <sub>I-O</sub> = 1kV <sub>DC</sub>                                    | 10 <sup>11</sup> |      |      | Ω    |
|            | Isolation Capacitance                                       | C <sub>I-O</sub>      | V = 0 V, f = 1 MHz                                                      |                  | 0.4  |      | pF   |
|            | Rise Time*3                                                 | t <sub>r</sub>        | V <sub>CC</sub> = 5 V, I <sub>C</sub> = 2 mA,<br>R <sub>L</sub> = 100 Ω |                  | 4    |      | μs   |
|            | Fall Time*3                                                 | t <sub>f</sub>        |                                                                         |                  | 5    |      |      |

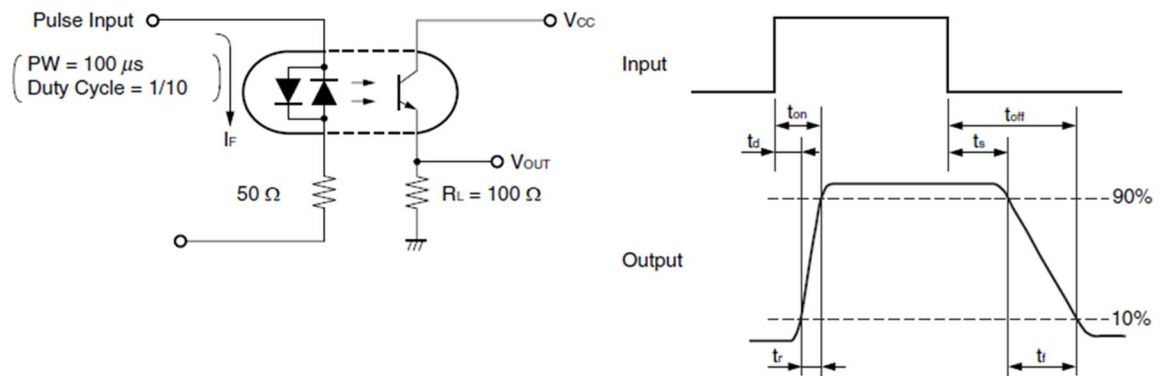
\*1. CTR rank

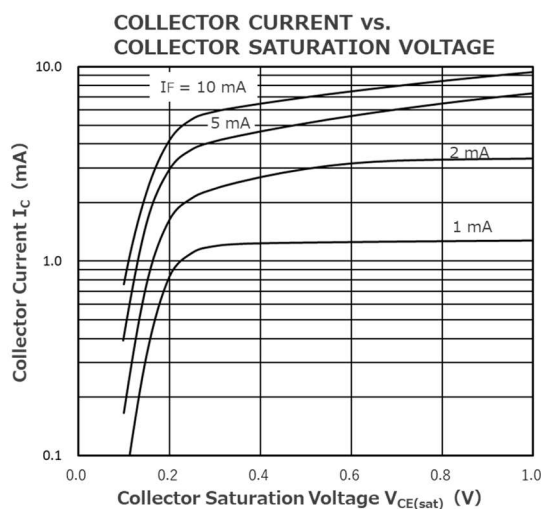
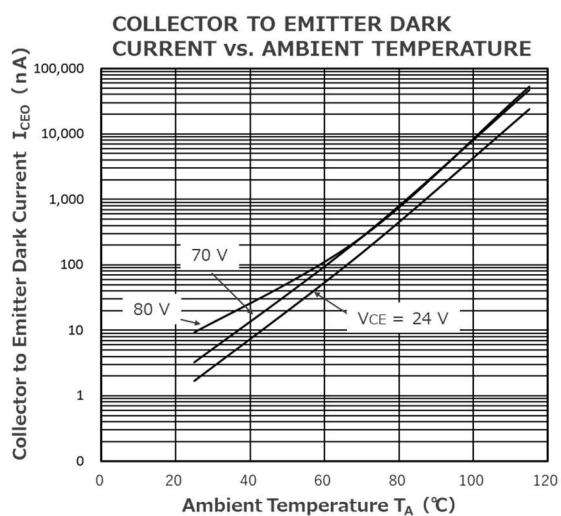
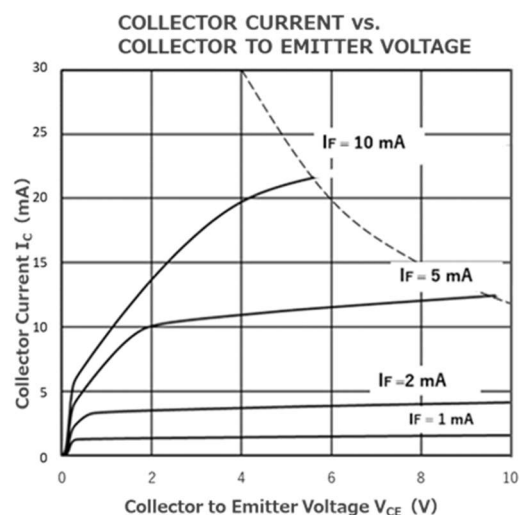
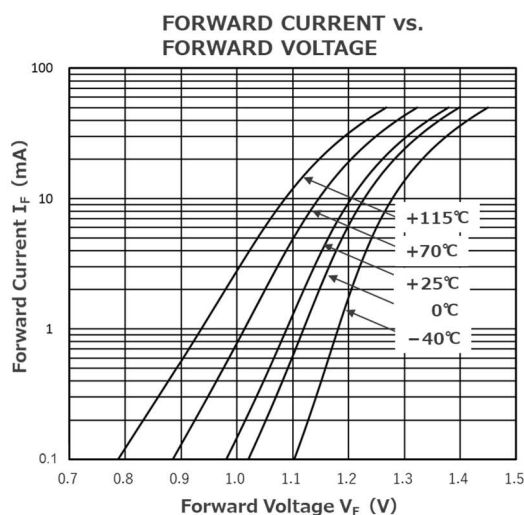
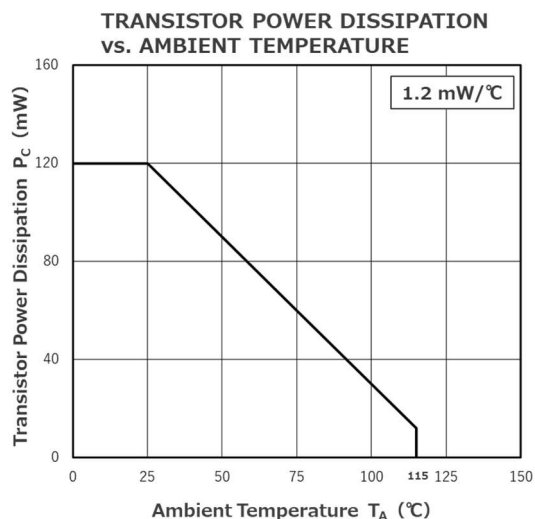
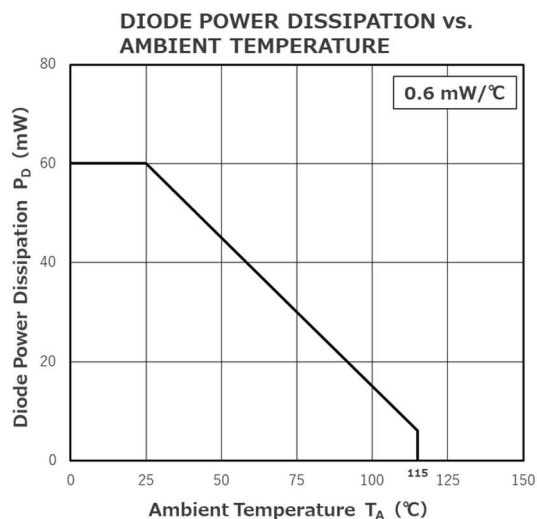
| CTR rank | CTR(%)    | Condition                                    |
|----------|-----------|----------------------------------------------|
| N        | 50 ~ 400  | I <sub>F</sub> = 5 mA, V <sub>CE</sub> = 5 V |
|          | 10 ~      | I <sub>F</sub> = 1 mA, V <sub>CE</sub> = 5 V |
| M        | 50 ~ 150  | I <sub>F</sub> = 5 mA, V <sub>CE</sub> = 5 V |
|          | 10 ~      | I <sub>F</sub> = 1 mA, V <sub>CE</sub> = 5 V |
| L        | 100 ~ 300 | I <sub>F</sub> = 5 mA, V <sub>CE</sub> = 5 V |
|          | 20 ~      | I <sub>F</sub> = 1 mA, V <sub>CE</sub> = 5 V |
| K        | 150 ~ 350 | I <sub>F</sub> = 5 mA, V <sub>CE</sub> = 5 V |
|          | 20 ~      | I <sub>F</sub> = 1 mA, V <sub>CE</sub> = 5 V |

\*2.  $CTR1 = I_{C1}/I_{F1}$ ,  $CTR2 = I_{C2}/I_{F2}$

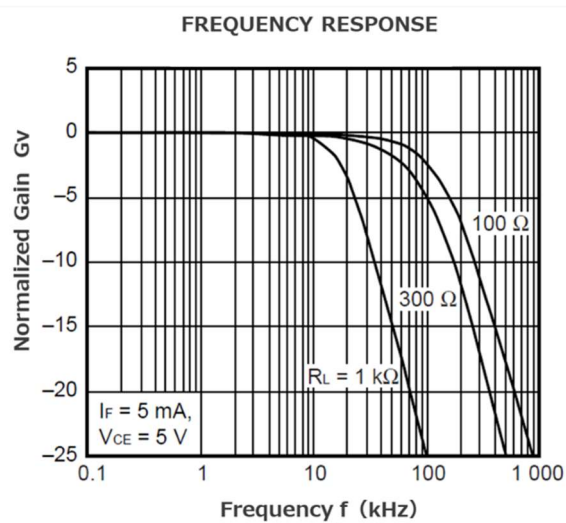
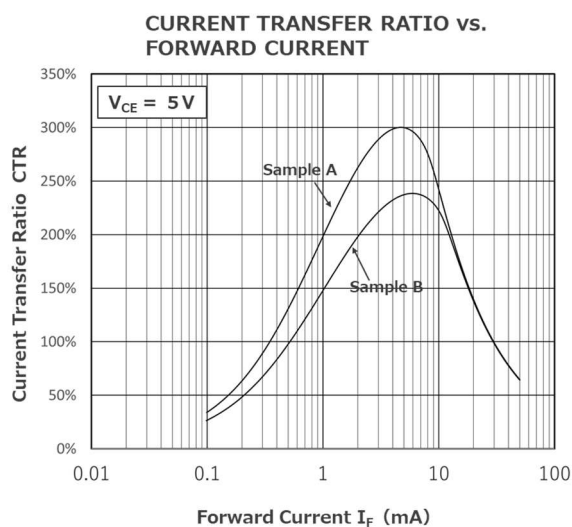
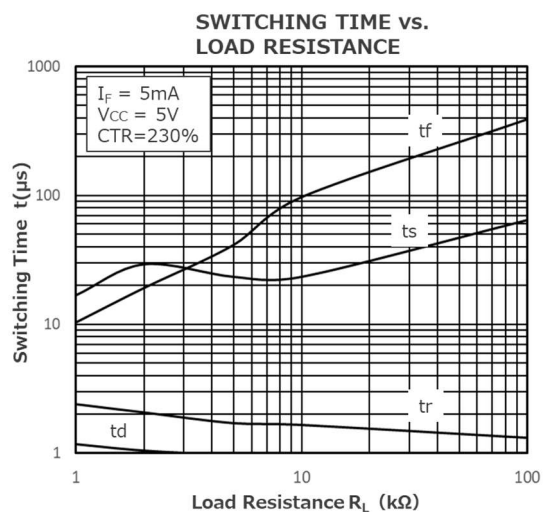
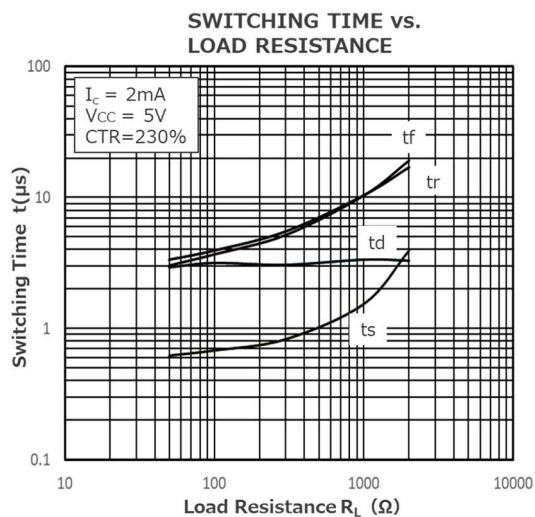
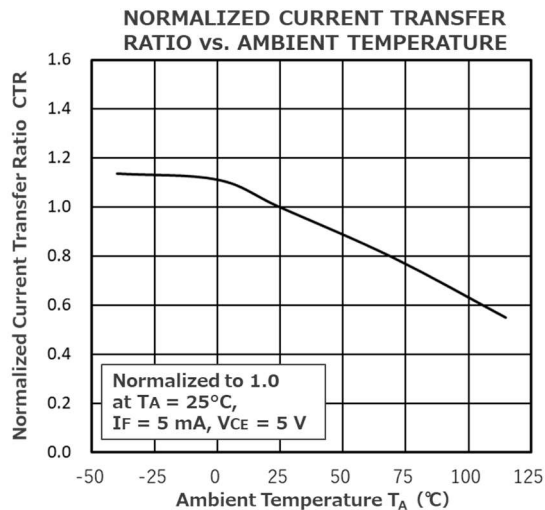
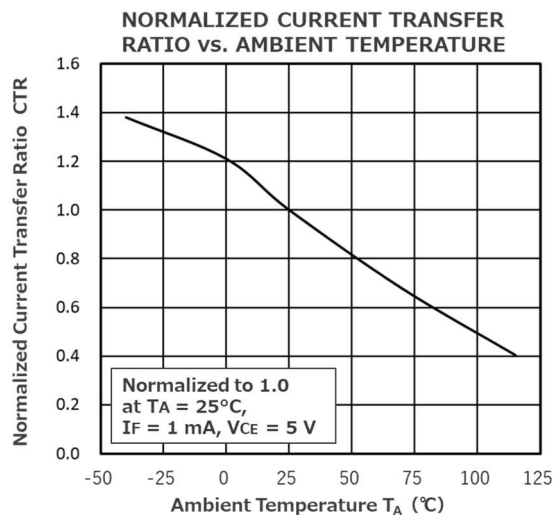


\*3. Test circuit for switching time



TYPICAL CHARACTERISTICS ( $T_A = +25^\circ\text{C}$ , unless otherwise specified)

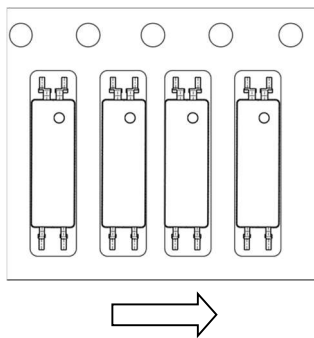
Remark The graphs indicate nominal characteristics.

TYPICAL CHARACTERISTICS ( $T_A = +25^\circ\text{C}$ , unless otherwise specified)

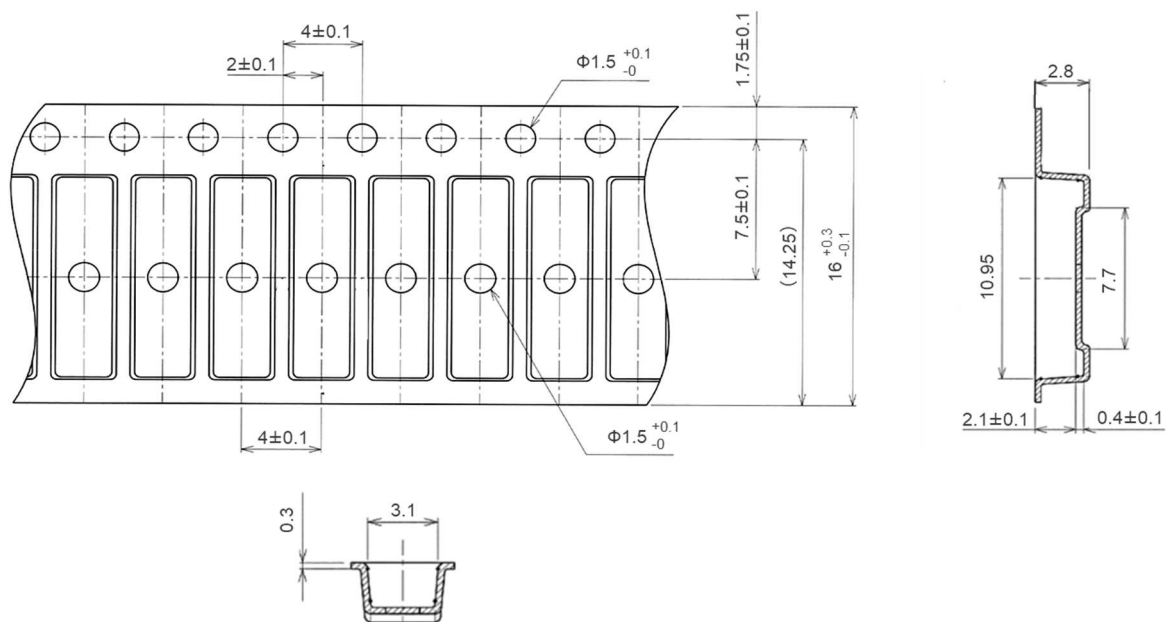
Remark The graphs indicate nominal characteristics.

## TAPING SPECIFICATIONS (UNIT: mm)

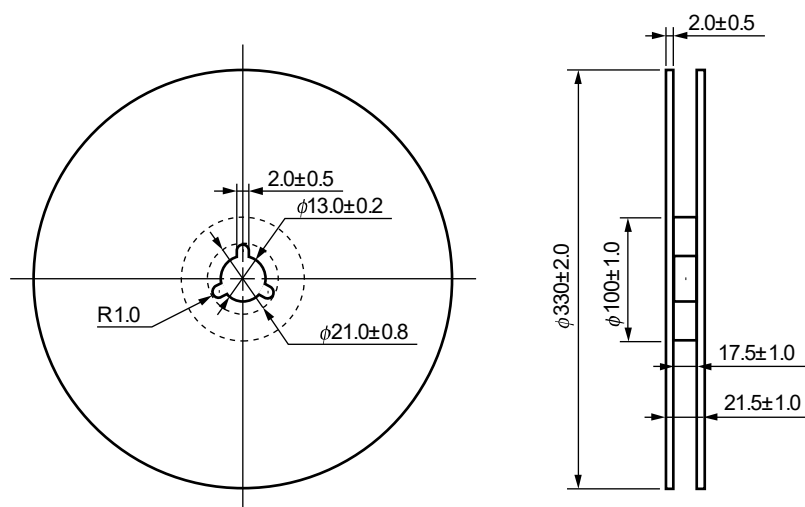
Tape Direction



Outline and Dimensions (Tape)



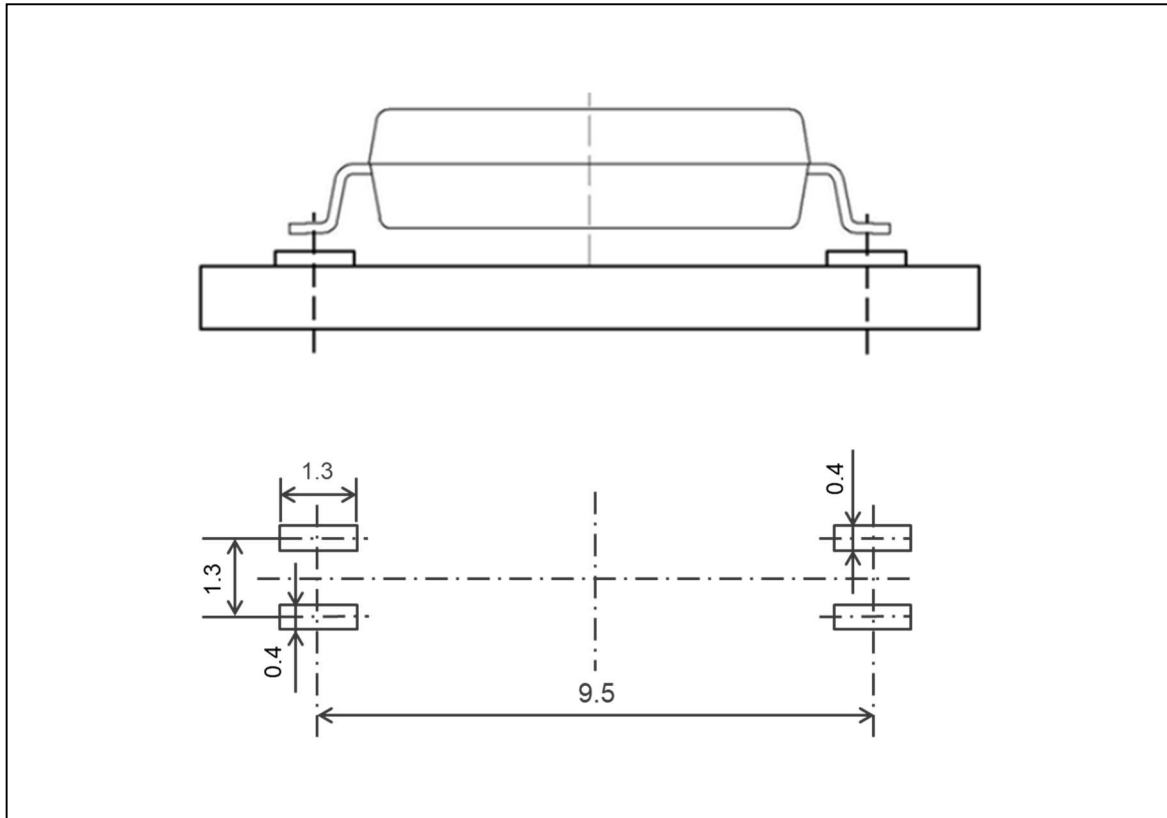
Outline and Dimensions (Reel)



Packing: 3 500 pcs/reel



## RECOMMENDED MOUNT PAD DIMENSIONS (UNIT : mm)



Remark All dimensions in this figure must be evaluated before use.

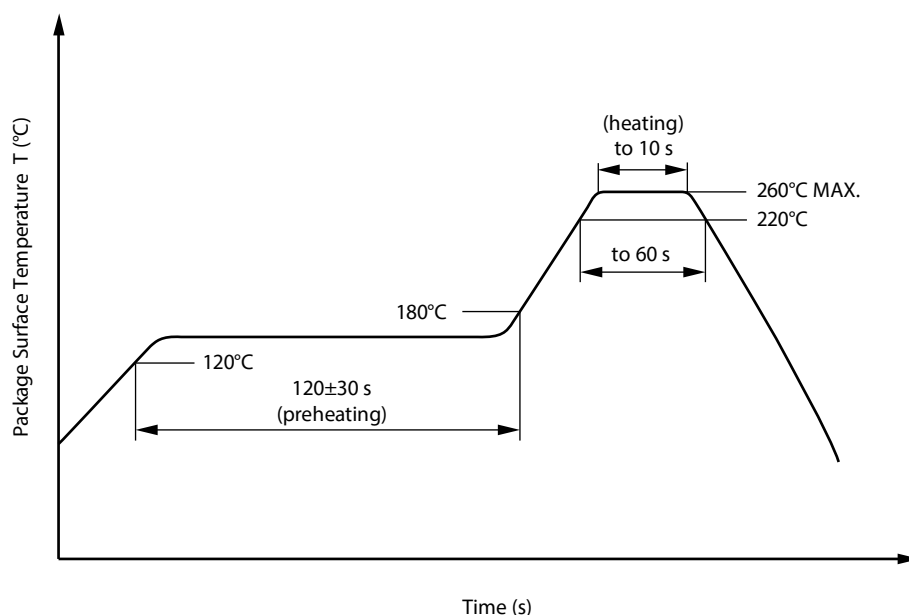
## NOTES ON HANDLING

### 1. Recommended soldering conditions

#### (1) Infrared reflow soldering

- Peak reflow temperature 260°C or below (package surface temperature)
- Time of peak reflow temperature 10 seconds or less
- Time of temperature higher than 220°C 60 seconds or less
- Time to preheat temperature from 120 to 180°C 120±30 s
- Number of reflows Three
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



#### (2) Wave soldering

- Temperature 260°C or below (molten solder temperature)
- Time 10 seconds or less
- Preheating conditions 120°C or below (package surface temperature)
- Number of times One (Allowed to be dipped in solder including plastic mold portion.)
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

#### (3) Soldering by Soldering Iron

- Peak Temperature (lead part temperature) 350°C or below
- Time (each pins) 3 seconds or less
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

(a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead

(b) Please be sure that the temperature of the package would not be heated over 100°C

#### (4) Cautions

- Flux Cleaning Avoid cleaning with Freon based or halogen-based (chlorinated etc.) solvents.
- Do not use fixing agents or coatings containing halogen-based substances.

### 2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output or between collector-emitters at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

**3. Measurement conditions of current transfer ratios (CTR), which differ according to photocoupler**

Check the setting values before use, since the forward current conditions at CTR measurement differ according to product.

When using products other than at the specified forward current, the characteristics curves may differ from the standard curves due to CTR value variations or the like. Therefore, check the characteristics under the actual operating conditions and thoroughly take variations or the like into consideration before use.

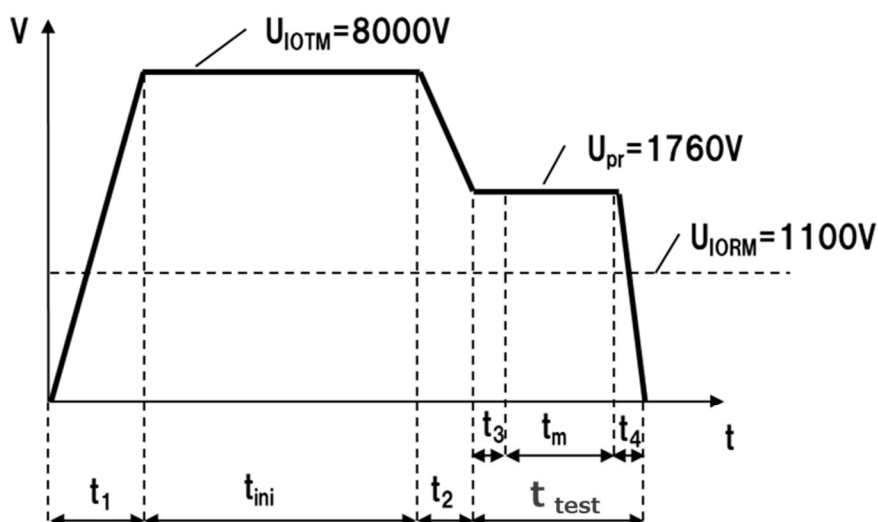
**USAGE CAUTIONS**

1. Protect against static electricity when handling.
2. Avoid storage at a high temperature and high humidity.

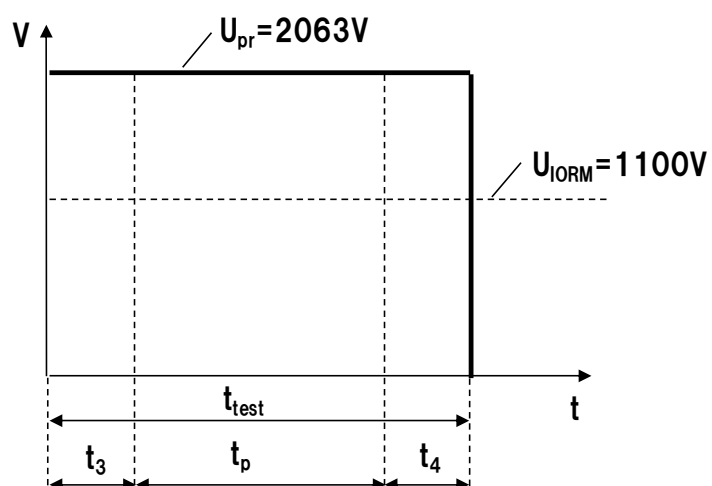
## SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

| Parameter                                                                                 | Symbol      | Rating          | Unit               |
|-------------------------------------------------------------------------------------------|-------------|-----------------|--------------------|
| Climatic test class (IEC 60068-1/DIN EN 60068-1)                                          |             | 40/115/21       |                    |
| Dielectric strength                                                                       |             |                 |                    |
| maximum operating isolation voltage                                                       | $U_{IORM}$  | 1 100           | $V_{peak}$         |
| Test voltage (partial discharge test, procedure a for type test and random test)          | $U_{pr}$    | 1 760           | $V_{peak}$         |
| $U_{pr} = 1.6 \times U_{IORM}$ , $P_d < 5 \text{ pC}$                                     |             |                 |                    |
| Test voltage (partial discharge test, procedure b for all devices)                        | $U_{pr}$    | 2 063           | $V_{peak}$         |
| $U_{pr} = 1.875 \times U_{IORM}$ , $P_d < 5 \text{ pC}$                                   |             |                 |                    |
| Highest permissible overvoltage                                                           | $U_{IOTM}$  | 8 000           | $V_{peak}$         |
| Degree of pollution (IEC 60664-1/DIN EN 60664-1 (VDE 0110-1))                             |             | 2               |                    |
| Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303-11))                         | CTI         | 400             |                    |
| Material group (IEC 60664-1/DIN EN 60664-1 (VDE 0110-1))                                  |             | II              |                    |
| Storage temperature range                                                                 | $T_{stg}$   | $-40 \sim +125$ | $^{\circ}\text{C}$ |
| Operating temperature range                                                               | $T_A$       | $-40 \sim +115$ | $^{\circ}\text{C}$ |
| Isolation resistance, minimum value                                                       |             |                 |                    |
| $V_{IO} = 500 \text{ V dc}$ at $T_A = 25^{\circ}\text{C}$                                 | Ris MIN.    | $10^{12}$       | $\Omega$           |
| $V_{IO} = 500 \text{ V dc}$ at $T_A \text{ MAX.}$ at least $100^{\circ}\text{C}$          | Ris MIN.    | $10^{11}$       | $\Omega$           |
| Safety maximum ratings (maximum permissible in case of fault, see thermal derating curve) |             |                 |                    |
| Package temperature                                                                       | $T_{si}$    | 175             | $^{\circ}\text{C}$ |
| Current (input current $I_F$ , $\Psi_i = 0$ )                                             | $I_{si}$    | 400             | mA                 |
| Power (output or total power dissipation)                                                 | $\Psi_{si}$ | 700             | mW                 |
| Isolation resistance $V_{IO} = 500 \text{ V dc}$ at $T_A = T_{si}$                        | Ris MIN.    | $10^9$          | $\Omega$           |

## Method a) Destructive Test, Type and Sample Test


 $t_1, t_2 = 1 \text{ to } 10 \text{ sec}$ 
 $t_3, t_4 = 1 \text{ sec}$ 
 $t_m \text{ (PARTIAL DISCHARGE)} = 10 \text{ sec}$ 
 $t_{test} = 12 \text{ sec}$ 
 $t_{ini} = 60 \text{ sec}$

## Method b) Non-destructive Test, 100% Production Test



$$t_3, t_4 = 0.1 \text{ sec}$$

$$t_p \text{ (PARTIAL DISCHARGE)} = 1.0 \text{ sec}$$

$$t_{test} = 1.2 \text{ sec}$$

**Caution**

GaAs Products

This product uses gallium arsenide (GaAs).

GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.

- Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
  1. Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
  2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
- Do not burn, destroy, cut, crush, or chemically dissolve the product.
- Do not lick the product or in any way allow it to enter the mouth.

All trademarks and registered trademarks are the property of their respective owners.

## Notice

1. Descriptions of circuits, software and other related information in this document are provided only to illustrate the operation of semiconductor products and application examples. You are fully responsible for the incorporation or any other use of the circuits, software, and information in the design of your product or system. Renesas Electronics disclaims any and all liability for any losses and damages incurred by you or third parties arising from the use of these circuits, software, or information.
  2. Renesas Electronics hereby expressly disclaims any warranties against and liability for infringement or any other claims involving patents, copyrights, or other intellectual property rights of third parties, by or arising from the use of Renesas Electronics products or technical information described in this document, including but not limited to, the product data, drawings, charts, programs, algorithms, and application examples.
  3. No license, express, implied or otherwise, is granted hereby under any patents, copyrights or other intellectual property rights of Renesas Electronics or others.
  4. You shall not alter, modify, copy, or reverse engineer any Renesas Electronics product, whether in whole or in part. Renesas Electronics disclaims any and all liability for any losses or damages incurred by you or third parties arising from such alteration, modification, copying or reverse engineering.
  5. Renesas Electronics products are classified according to the following two quality grades: "Standard" and "High Quality". The intended applications for each Renesas Electronics product depends on the product's quality grade, as indicated below.

"Standard": Computers; office equipment; communications equipment; test and measurement equipment; audio and visual equipment; home electronic appliances; machine tools; personal electronic equipment; industrial robots; etc.

"High Quality": Transportation equipment (automobiles, trains, ships, etc.); traffic control (traffic lights); large-scale communication equipment; key financial terminal systems; safety control equipment; etc.

Unless expressly designated as a high reliability product or a product for harsh environments in a Renesas Electronics data sheet or other Renesas Electronics document, Renesas Electronics products are not intended or authorized for use in products or systems that may pose a direct threat to human life or bodily injury (artificial life support devices or systems; surgical implantations; etc.), or may cause serious property damage (space system; undersea repeaters; nuclear power control systems; aircraft control systems; key plant systems; military equipment; etc.). Renesas Electronics disclaims any and all liability for any damages or losses incurred by you or any third parties arising from the use of any Renesas Electronics product that is inconsistent with any Renesas Electronics data sheet, user's manual or other Renesas Electronics document.
  6. When using Renesas Electronics products, refer to the latest product information (data sheets, user's manuals, application notes, "General Notes for Handling and Using Semiconductor Devices" in the reliability handbook, etc.), and ensure that usage conditions are within the ranges specified by Renesas Electronics with respect to maximum ratings, operating power supply voltage range, heat dissipation characteristics, installation, etc. Renesas Electronics disclaims any and all liability for any malfunctions, failure or accident arising out of the use of Renesas Electronics products outside of such specified ranges.
  7. Although Renesas Electronics endeavors to improve the quality and reliability of Renesas Electronics products, semiconductor products have specific characteristics, such as the occurrence of failure at a certain rate and malfunctions under certain use conditions. Unless designated as a high reliability product or a product for harsh environments in a Renesas Electronics data sheet or other Renesas Electronics document, Renesas Electronics products are not subject to radiation resistance design. You are responsible for implementing safety measures to guard against the possibility of bodily injury, injury or damage caused by fire, and/or danger to the public in the event of a failure or malfunction of Renesas Electronics products, such as safety design for hardware and software, including but not limited to redundancy, fire control and malfunction prevention, appropriate treatment for aging degradation or any other appropriate measures. Because the evaluation of microcomputer software alone is very difficult and impractical, you are responsible for evaluating the safety of the final products or systems manufactured by you.
  8. Please contact a Renesas Electronics sales office for details as to environmental matters such as the environmental compatibility of each Renesas Electronics product. You are responsible for carefully and sufficiently investigating applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive, and using Renesas Electronics products in compliance with all these applicable laws and regulations. Renesas Electronics disclaims any and all liability for damages or losses occurring as a result of your noncompliance with applicable laws and regulations.
  9. Renesas Electronics products and technologies shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable domestic or foreign laws or regulations. You shall comply with any applicable export control laws and regulations promulgated and administered by the governments of any countries asserting jurisdiction over the parties or transactions.
  10. It is the responsibility of the buyer or distributor of Renesas Electronics products, or any other party who distributes, disposes of, or otherwise sells or transfers the product to a third party, to notify such third party in advance of the contents and conditions set forth in this document.
  11. This document shall not be reprinted, reproduced or duplicated in any form, in whole or in part, without prior written consent of Renesas Electronics.
  12. Please contact a Renesas Electronics sales office if you have any questions regarding the information contained in this document or Renesas Electronics products.
- (Note 1) "Renesas Electronics" as used in this document means Renesas Electronics Corporation and also includes its directly or indirectly controlled subsidiaries.
- (Note 2) "Renesas Electronics product(s)" means any product developed or manufactured by or for Renesas Electronics.

(Rev.4.0-1 November 2017)



### SALES OFFICES

### Renesas Electronics Corporation

<http://www.renesas.com>

Refer to "<http://www.renesas.com/>" for the latest and detailed information.

**Renesas Electronics Corporation**  
TOYOSU FORESIA, 3-2-24 Toyosu, Koto-ku, Tokyo 135-0061, Japan

**Renesas Electronics America Inc.**  
1001 Murphy Ranch Road, Milpitas, CA 95035, U.S.A.  
Tel: +1-408-432-8888, Fax: +1-408-434-5351

**Renesas Electronics Canada Limited**  
9251 Yonge Street, Suite 8309 Richmond Hill, Ontario Canada L4C 9T3  
Tel: +1-905-237-2004

**Renesas Electronics Europe GmbH**  
Arcadiastrasse 10, 40472 Düsseldorf, Germany  
Tel: +49-211-6503-0, Fax: +49-211-6503-1327

**Renesas Electronics (China) Co., Ltd.**  
Room 101-T01, Floor 1, Building 7, Yard No. 7, 8th Street, Shangdi, Haidian District, Beijing 100085, China  
Tel: +86-10-8235-1155, Fax: +86-10-8235-7679

**Renesas Electronics (Shanghai) Co., Ltd.**  
Unit 301, Tower A, Central Towers, 555 Langao Road, Putuo District, Shanghai 200333, China  
Tel: +86-21-2226-0888, Fax: +86-21-2226-0999

**Renesas Electronics Hong Kong Limited**  
Unit 1601-1611, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong  
Tel: +852-2265-6688, Fax: +852 2886-9022

**Renesas Electronics Taiwan Co., Ltd.**  
13F, No. 363, Fu Shing North Road, Taipei 10543, Taiwan  
Tel: +886-2-8175-9600, Fax: +886 2-8175-9670

**Renesas Electronics Singapore Pte. Ltd.**  
80 Bendemeer Road, Unit #06-02 Hyflux Innovation Centre, Singapore 339949  
Tel: +65-6213-0200, Fax: +65-6213-0300

**Renesas Electronics Malaysia Sdn.Bhd.**  
Unit No 3A-1 Level 3A Tower 8 UOA Business Park, No 1 Jalan Pengaturcara U1/51A, Seksyen U1, 40150 Shah Alam, Selangor, Malaysia  
Tel: +60-3-5022-1288, Fax: +60-3-5022-1290

**Renesas Electronics India Pvt. Ltd.**  
No.777C, 100 Feet Road, HAL 2nd Stage, Indiranagar, Bangalore 560 038, India  
Tel: +91-80-67208700

**Renesas Electronics Korea Co., Ltd.**  
17F, KAMCO Yangjae Tower, 262, Gangnam-daero, Gangnam-gu, Seoul, 06265 Korea  
Tel: +82-2-558-3737, Fax: +82-2-558-5338